

MJE170/171/172

Low Power Audio Amplifier Low Current, High Speed Switching Applications



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Paramet	ter	Value	Units
V _{CBO}	Collector-Base Voltage	: MJE170	- 60	V
020		: MJE171	- 80	V
		: MJE172	- 100	V
V _{CEO}	Collector-Emitter Voltage	: MJE170	- 40	V
		: MJE171	- 60	V
		: MJE172	- 80	V
V _{EBO}	Emitter-Base Voltage		- 7	V
Ic	Collector Current (DC)		- 3	Α
I _{CP}	Collector Current (Pulse)		- 6	Α
I _B	Base Current		- 1	Α
P _C	Collector Dissipation (T _C =25°C)		12.5	W
	Collector Dissipation (T _a =25°C)		1.5	W
T _J	Junction Temperature		150	°C
T _{STG}	Storage Temperature		- 65 ~ 150	°C

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CEO}	Collector-Emitter Breaksown Voltage : MJE170 : MJE171 : MJE172	I _C = 10mA, I _B = 0	-40 -60 -80		V V V
Ісво	Collector Cut-off Current : MJE170 : MJE171 : MJE172 : MJE170 : MJE170 : MJE171 : MJE171 : MJE172	$\begin{split} &V_{CB} = -60 \text{V}, I_B = 0 \\ &V_{CB} = -80 \text{V}, I_E = 0 \\ &V_{CB} = -100 \text{V}, I_E = 0 \\ &V_{CB} = -60 \text{V}, I_E = 0, @T_C = 150 ^{\circ}\text{C} \\ &V_{CB} = -80 \text{V}, I_E = 0, @T_C = 150 ^{\circ}\text{C} \\ &V_{CB} = -100 \text{V}, I_E = 0, @T_C = 150 ^{\circ}\text{C} \end{split}$		-0.1 -0.1 -0.1 -0.1 -0.1	μΑ μΑ μΑ mA mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = -7V, I_{C} = 0$		-0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = -1V$, $I_{C} = -100$ mA $V_{CE} = -1V$, $I_{C} = -500$ mA $V_{CE} = -1V$, $I_{C} = -1.5$ A	50 30 12	250	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = - 500mA, I _B = - 50mA I _C = - 1.5A, I _B = - 150mA I _C = - 3A, I _B = - 600mA		-0.3 -0.9 -1.7	V V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = - 1.5A, I _B = - 150mA I _C = - 3A, I _B = - 600mA		-1.5 -2.0	V V
V _{BE} (on)	Base-Emitter ON Voltage	V _{CE} = - 1V, I _C = - 500mA		-1.2	V
f _T	Current Gain Bandwidth Product	V _{CE} = - 10V, I _C = - 100mA	50		MHz
C _{ob}	Output Capacitance	$V_{CB} = -10V, I_E = 0, f = 0.1MHz$		50	pF

Typical Charactristics

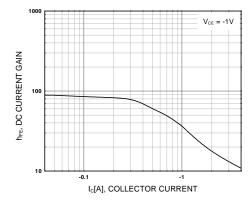


Figure 1. DC current Gain

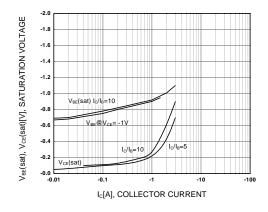


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

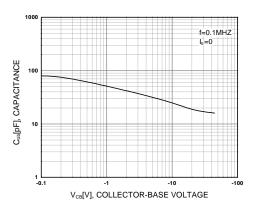


Figure 3. Collector Output Capacitance

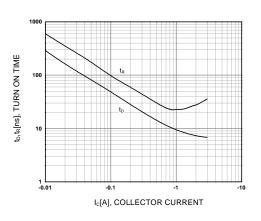


Figure 4. Turn On Time

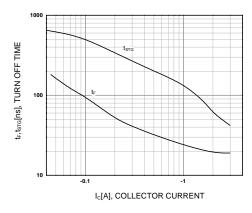


Figure 5. Turn Off Time

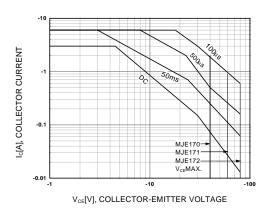


Figure 6. Safe Operating Area

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Typical Characteristics (Continued)

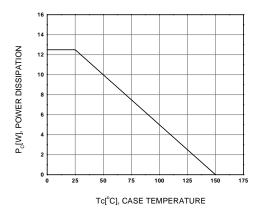
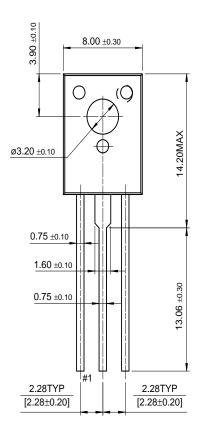
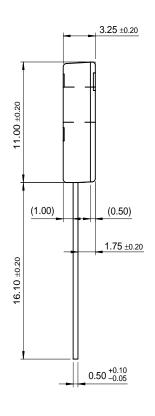


Figure 7. DC current Gain

Package Demensions

TO-126





Dimensions in Millimeters

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